## NSN 5961-01-314-1543

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-314-1543 **Inclosure Material:** Metal **Overall Length:** Between 0.169 inches and 0.180 inches **Terminal Length:** Between 0.500 inches and 0.560 inches **Overall Diameter:** 0.360 inches **Function For Which Designed:** Rectifier Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-39 **Mounting Method: Terminal Terminal Circle Diameter:** Between 0.190 inches and 0.210 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 repetitive peak reverse voltage and 45.0 working peak reverse voltage, peak total value and 54.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 2.00 amperes operating voltage dc and 4.00 amperes forward current, average and 80.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No